- Compare Two 8-Bit Words
- 100-kΩ Pullup Resistors Are on the Q Inputs
- Package Options Include Plastic Small-Outline (DW) and Ceramic Flat (W) Packages, Ceramic Chip Carriers (FK), and Standard Plastic (N) and Ceramic (J) 300-mil DIPs

#### description

These magnitude comparators perform comparisons of two 8-bit binary or BCD words. The 'HC682 feature  $100-k\Omega$  pullup termination resistors on the Q inputs for analog or switch data.

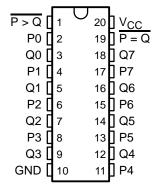
The SN54HC682 is characterized for operation over the full military temperature range of –55°C to 125°C. The SN74HC682 is characterized for operation from –40°C to 85°C.

#### **FUNCTION TABLE**

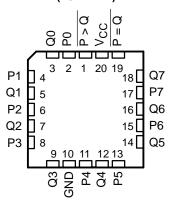
DATA	OUTPUTS						
INPUTS P, Q	P = Q	P > Q					
P = Q	L	Н					
P > Q	Н	L					
P < Q	н	Н					

The  $\overline{P}$  <  $\overline{Q}$  function can be generated by applying  $\overline{P}$  =  $\overline{Q}$  and  $\overline{P}$  >  $\overline{Q}$  to a 2-input NAND gate.

SN54HC682...J OR W PACKAGE SN74HC682...DW OR N PACKAGE (TOP VIEW)



# SN54HC682 . . . FK PACKAGE (TOP VIEW)

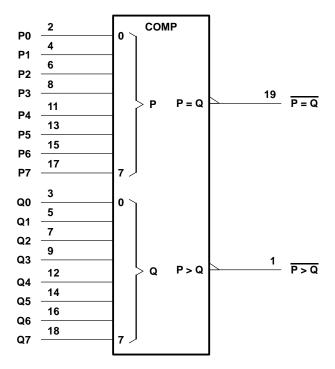




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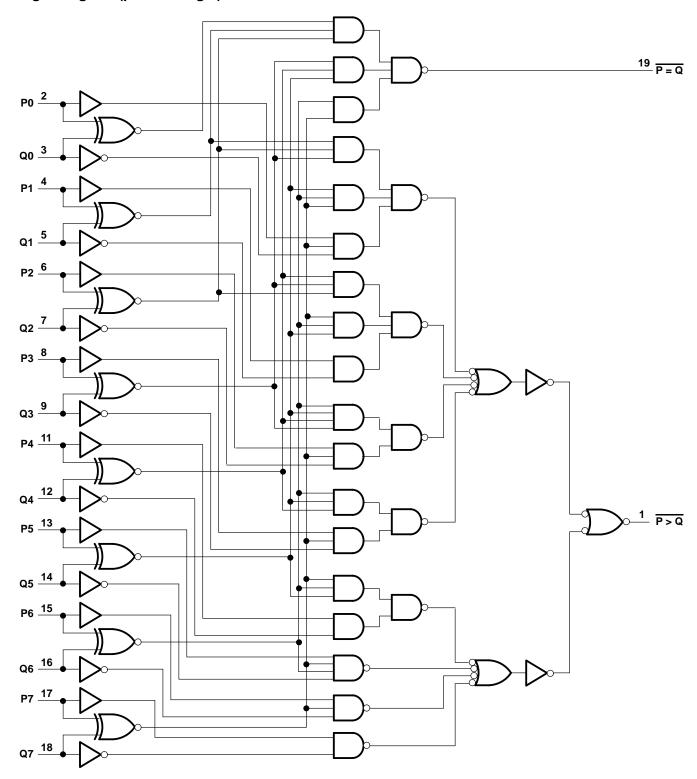
### logic symbol†



<sup>&</sup>lt;sup>†</sup>This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.



# logic diagram (positive logic)





### SN54HC682, SN74HC682 8-BIT MAGNITUDE COMPARATORS

SCLS018C - MARCH 1984 - REVISED MAY 1997

#### absolute maximum ratings over operating free-air temperature range†

Supply voltage range, V <sub>CC</sub>		0.5	$\mbox{V}$ to 7 $\mbox{V}$
Input clamp current, IIK (VI < 0 or VI > VCC) (se	ee Note 1)		$\pm 20 \ mA$
Output clamp current, I <sub>OK</sub> (V <sub>O</sub> < 0 or V <sub>O</sub> > V <sub>CO</sub>			
Continuous output current, $I_O$ ( $V_O = 0$ to $V_{CC}$ )			$\pm 25~\text{mA}$
Continuous current through V <sub>CC</sub> or GND			$\pm 50 \ mA$
	DW package		97°C/W
	N package		67°C/W
Storage temperature range, T <sub>stg</sub>		-65°C t	o 150°C

<sup>†</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

#### recommended operating conditions

			SI	SN54HC682		SN74HC682			UNIT
			MIN	NOM	MAX	MIN	NOM	MAX	UNII
VCC	Supply voltage		2	5	6	2	5	6	V
V <sub>IH</sub> High-level input voltage		V <sub>CC</sub> = 2 V	1.5			1.5			
	$V_{CC} = 4.5 \text{ V}$	3.15		7	3.15			V	
		V <sub>CC</sub> = 6 V	4.2		\ </td <td>4.2</td> <td></td> <td></td> <td></td>	4.2			
	Low-level input voltage	V <sub>CC</sub> = 2 V	0	F	0.5	0		0.5	V
$V_{IL}$		V <sub>CC</sub> = 4.5 V	0	,0	1.35	0		1.35	
		V <sub>CC</sub> = 6 V	0	0,	1.8	0		1.8	
٧ <sub>I</sub>	Input voltage		0.4	?	VCC	0		VCC	V
٧o	Output voltage		0		VCC	0		VCC	V
		V <sub>CC</sub> = 2 V	0		1000	0		1000	
t <sub>t</sub>	Input transition (rise and fall) time	V <sub>CC</sub> = 4.5 V	0		500	0		500	ns
		V <sub>CC</sub> = 6 V	0		400	0		400	
TA	Operating free-air temperature		-55		125	-40		85	°C

<sup>2.</sup> The package thermal impedance is calculated in accordance with JESD 51, except for through-hole packages, which use a trace length of zero.

# electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS		vcc	T <sub>A</sub> = 25°C			SN54HC682		SN74HC682		UNIT
PARAMETER	1231 CC	TEST CONDITIONS		MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNIT
			2 V	1.9	1.998		1.9		1.9		
		I <sub>OH</sub> = -20 μA	4.5 V	4.4	4.499		4.4		4.4		
Voн	VI = VIH or VIL		6 V	5.9	5.999		5.9		5.9		V
		$I_{OH} = -4 \text{ mA}$	4.5 V	3.98	4.3		3.7		3.84		
		$I_{OH} = -5.2 \text{ mA}$	6 V	5.48	5.8		5.2	<sup>E</sup> h	5.34		
VoL	VI = VIH or VIL	I <sub>OL</sub> = 20 μA	2 V		0.002	0.1		0.1		0.1	V
			4.5 V		0.001	0.1		0.1		0.1	
			6 V		0.001	0.1	ζ,	0.1		0.1	
		$I_{OL} = 4 \text{ mA}$	4.5 V		0.17	0.26	20	0.4		0.33	
		$I_{OL} = 5.2 \text{ mA}$	6 V		0.15	0.26	O <sub>V</sub>	0.4		0.33	
lін	$V_I = V_{CC}$		6 V		0.1	100	y	1000		1000	nA
1	V: - 0	Q inputs	6 V		-50	-90		-160		-140	μΑ
¹ı∟	V <sub>I</sub> = 0	All other inputs	6 V		-0.1	-100		-1000		-1000	nA
Icc	$V_I = V_{CC}$ or 0,	IO = 0	6 V		480	700		1300		1100	μΑ
C <sub>i</sub>			2 V to 6 V		3	10		10		10	pF

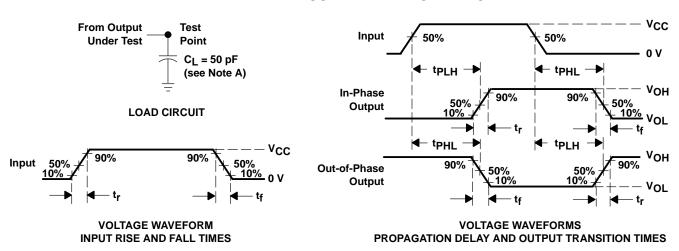
# switching characteristics over recommended operating free-air temperature range, $C_L$ = 50 pF (unless otherwise noted) (see Figure 1)

PARAMETER	FROM	FROM TO		T,	գ = 25°C	;	SN54HC	682	SN74H	C682	UNIT
PARAMETER	(INPUT)	(OUTPUT)	Vcc	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNII
t <sub>pd</sub> P or Q Any	2 V		130	275		413		344			
	Any	4.5 V		26	55	70	88		69	ns	
	·		6 V		22	47	Q	70		58	
		2 V		38	75	3	110		95		
t <sub>t</sub>		Any	4.5 V		8	8 15 8 2	22		19	ns	
			6 V		6	13	b'd	19		16	

# operating characteristics, $T_A = 25^{\circ}C$

	PARAMETER  Cod Power dissination canacitance		TYP	UNIT
C <sub>pd</sub>	Power dissipation capacitance	No load	40	pF

#### PARAMETER MEASUREMENT INFORMATION



NOTES: A.  $C_L$  includes probe and test-fixture capacitance.

- B. Phase relationships between waveforms were chosen arbitrarily. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  1 MHz,  $Z_O = 50 \ \Omega$ ,  $t_f = 6 \ ns$ ,  $t_f = 6 \ ns$ .
- C. The outputs are measured one at a time with one input transition per measurement.
- D.  $t_{PLH}$  and  $t_{PHL}$  are the same as  $t_{pd}$ .

Figure 1. Load Circuit and Voltage Waveforms



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